

BAP1321LX

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Silicon PIN diode

Rev. 01 — 30 July 2007

Product data sheet

1. Product profile

1.1 General description

Planar PIN diode in a SOD882T leadless ultra small plastic SMD package.

1.2 Features

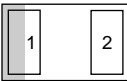

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- Low diode forward resistance
- Very low series inductance
- For applications up to 3 GHz

1.3 Applications

- RF attenuators and switches

2. Pinning information

Table 1. Discrete pinning

| Pin | Description | Simplified outline | Symbol |
|-----|-------------|---|---|
| 1 | cathode | [1] | |
| 2 | anode |  |  |
| | | Transparent top view | sym006 |

[1] The marking bar indicates the cathode.

3. Ordering information

Table 2. Ordering information

| Type number | Package | | |
|-------------|---------|--|---------|
| | Name | Description | Version |
| BAP1321LX | - | leadless ultra small plastic package; 2 terminals; body 1 × 0.6 × 0.4 mm | SOD882T |

4. Marking

Table 3. Marking

| Type number | Marking code |
|-------------|--------------|
| BAP1321LX | LH |

5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|-------------------------|-----|------|------|
| V_R | reverse voltage | | - | 60 | V |
| I_F | forward current | | - | 100 | mA |
| P_{tot} | total power dissipation | $T_{sp} = 90\text{ °C}$ | - | 130 | mW |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| T_j | junction temperature | | -65 | +150 | °C |

6. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Typ | Unit |
|----------------|--|------------|-----|------|
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | | 74 | K/W |

7. Characteristics

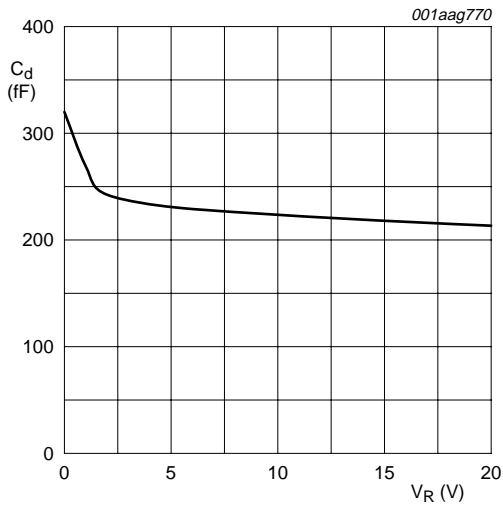
Table 6. Characteristics

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------|--------------------------|---|-----|------|------|----------|
| V_F | forward voltage | $I_F = 50\text{ mA}$ | - | 0.95 | 1.1 | V |
| I_R | reverse current | $V_R = 60\text{ V}$ | - | - | 100 | nA |
| C_d | diode capacitance | see Figure 1 ; $f = 1\text{ MHz}$; | | | | |
| | | $V_R = 0\text{ V}$ | - | 0.32 | - | pF |
| | | $V_R = 1\text{ V}$ | - | 0.27 | 0.38 | pF |
| | | $V_R = 20\text{ V}$ | - | 0.21 | 0.28 | pF |
| r_D | diode forward resistance | see Figure 2 ; $f = 100\text{ MHz}$; | | | | |
| | | $I_F = 0.5\text{ mA}$ | - | 3.3 | 5.0 | Ω |
| | | $I_F = 1\text{ mA}$ | - | 2.4 | 3.6 | Ω |
| | | $I_F = 10\text{ mA}$ | - | 1.2 | 1.8 | Ω |
| | | $I_F = 100\text{ mA}$ | - | 0.9 | 1.3 | Ω |
| ISL | isolation | see Figure 3 ; $V_R = 0\text{ V}$; | | | | |
| | | $f = 900\text{ MHz}$ | - | 17 | - | dB |
| | | $f = 1800\text{ MHz}$ | - | 12 | - | dB |
| | | $f = 2450\text{ MHz}$ | - | 10 | - | dB |

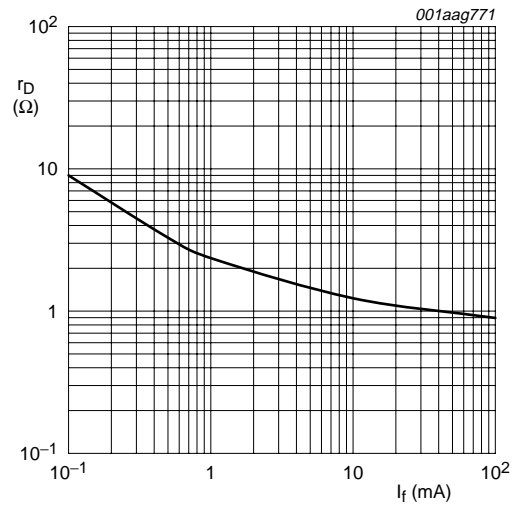
Table 6. Characteristics ...continued
 $T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|--------------------------|--|-----|------|-----|---------------|
| L_{ins} | insertion loss | see Figure 4 ; $I_F = 0.5\text{ mA}$; | | | | |
| | | $f = 900\text{ MHz}$ | - | 0.25 | - | dB |
| | | $f = 1800\text{ MHz}$ | - | 0.26 | - | dB |
| | | $f = 2450\text{ MHz}$ | - | 0.27 | - | dB |
| L_{ins} | insertion loss | see Figure 4 ; $I_F = 1\text{ mA}$; | | | | |
| | | $f = 900\text{ MHz}$ | - | 0.19 | - | dB |
| | | $f = 1800\text{ MHz}$ | - | 0.20 | - | dB |
| | | $f = 2450\text{ MHz}$ | - | 0.21 | - | dB |
| L_{ins} | insertion loss | see Figure 4 ; $I_F = 10\text{ mA}$; | | | | |
| | | $f = 900\text{ MHz}$ | - | 0.11 | - | dB |
| | | $f = 1800\text{ MHz}$ | - | 0.13 | - | dB |
| | | $f = 2450\text{ MHz}$ | - | 0.14 | - | dB |
| L_{ins} | insertion loss | see Figure 4 ; $I_F = 100\text{ mA}$; | | | | |
| | | $f = 900\text{ MHz}$ | - | 0.09 | - | dB |
| | | $f = 1800\text{ MHz}$ | - | 0.11 | - | dB |
| | | $f = 2450\text{ MHz}$ | - | 0.12 | - | dB |
| τ_L | charge carrier life time | when switched from $I_F = 10\text{ mA}$ to $I_R = 6\text{ mA}$; $R_L = 100\text{ }\Omega$; measured at $I_R = 3\text{ mA}$ | - | 0.48 | - | μs |
| L_S | series inductance | $I_F = 100\text{ mA}$; $f = 100\text{ MHz}$ | - | 0.4 | - | nH |



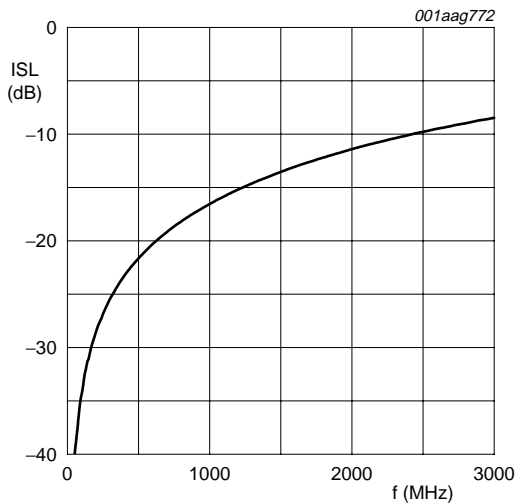
f = 1 MHz; T_j = 25 °C.

Fig 1. Diode capacitance as a function of reverse voltage; typical values



f = 100 MHz; T_j = 25 °C.

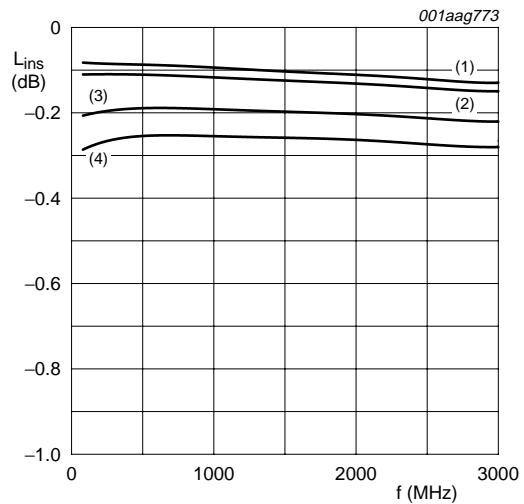
Fig 2. Forward resistance as a function of forward current; typical values



T_{amb} = 25 °C

Diode zero biased and inserted in series with a 50 Ω stripline circuit

Fig 3. Isolation of the diode as a function of frequency; typical values



T_{amb} = 25 °C

- (1) I_F = 100 mA
- (2) I_F = 10 mA
- (3) I_F = 1 mA
- (4) I_F = 0.5 mA

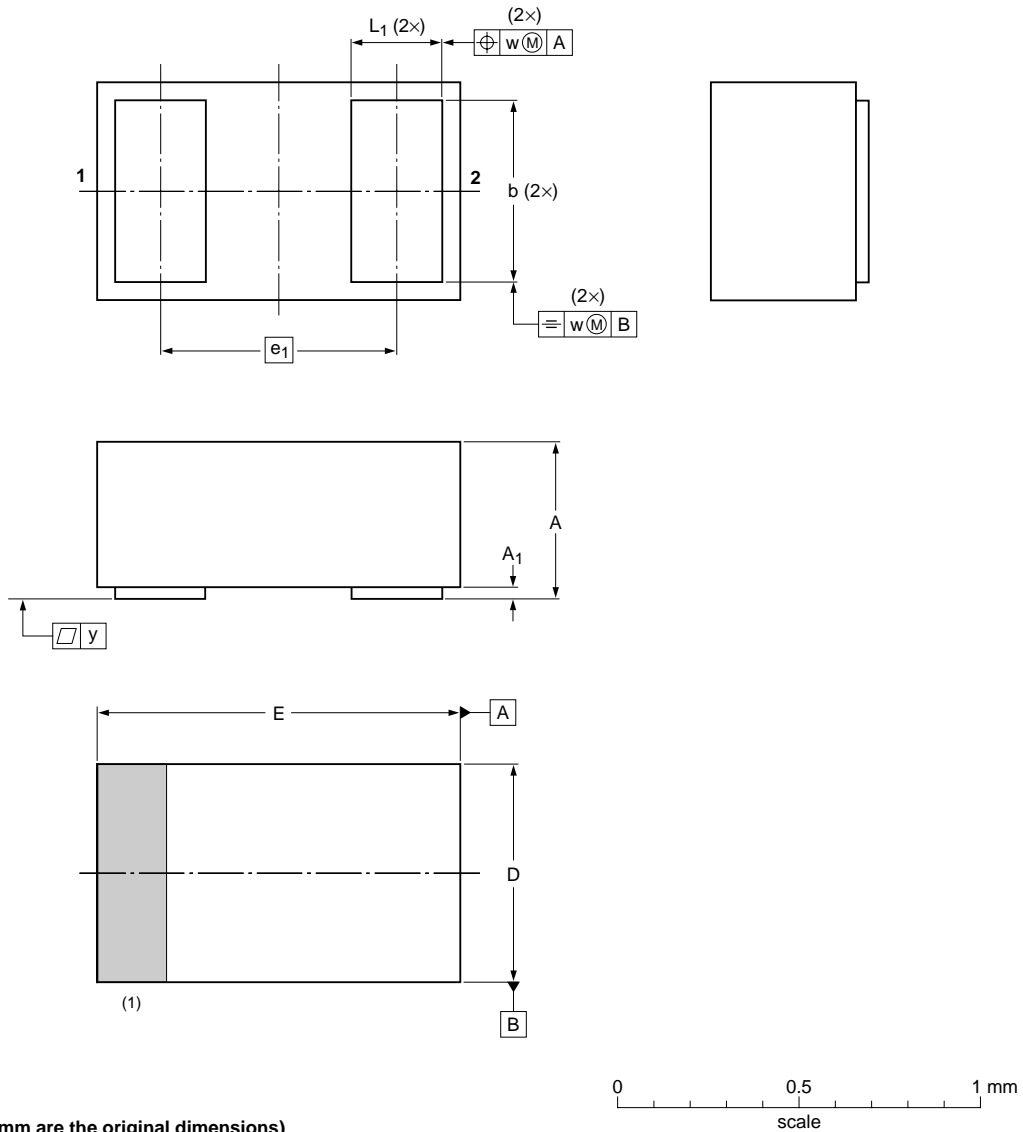
Diode inserted in series with a 50 Ω stripline circuit and biased via the analyzer Tee network

Fig 4. Insertion loss of the diode as a function of frequency; typical values

8. Package outline

Leadless ultra small plastic package; 2 terminals; body 1 x 0.6 x 0.4 mm

SOD882T



DIMENSIONS (mm are the original dimensions)

| UNIT | A | A ₁ max | b | D | E | e ₁ | L ₁ | w | y |
|------|--------------|-----------------------|--------------|--------------|--------------|----------------|----------------|-----|------|
| mm | 0.40 0.36 | 0.04 | 0.55 0.45 | 0.65 0.55 | 1.05 0.95 | 0.65 | 0.30 0.22 | 0.1 | 0.03 |

Note

1. The marking bar indicates the cathode

| OUTLINE VERSION | REFERENCES | | | EUROPEAN PROJECTION | ISSUE DATE |
|--------------------|------------|-------|-------|------------------------|----------------------|
| | IEC | JEDEC | JEITA | | |
| SOD882T | | | | | 04-12-14 06-04-12 |

Fig 5. Package outline SOD882T

9. Abbreviations

Table 7. Abbreviations

| Acronym | Description |
|---------|---------------------------|
| PIN | P-type, Intrinsic, N-type |
| SMD | Surface Mounted Device |
| RF | Radio Frequency |

10. Revision history

Table 8. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-------------|--------------|--------------------|---------------|------------|
| BAP1321LX_1 | 20070730 | Product data sheet | - | - |

11. Legal information

11.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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